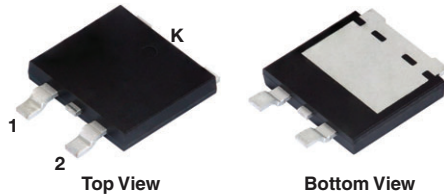


Dual High-Voltage TMBS® (Trench MOS Barrier Schottky) Rectifier

 Ultra Low $V_F = 0.36\text{ V}$ at $I_F = 5\text{ A}$

eSMP® Series SMPD (TO-263AC)



LINKS TO ADDITIONAL RESOURCES


[3D Models](#)

PRIMARY CHARACTERISTICS

| | |
|--|-----------------|
| $I_{F(AV)}$ | 2 x 30 A |
| V_{RRM} | 100 V |
| I_{FSM} | 320 A |
| V_F at $I_F = 30\text{ A}$ ($T_A = 125\text{ °C}$) | 0.66 V |
| T_J max. | 150 °C |
| Package | SMPD (TO-263AC) |
| Circuit configuration | Common cathode |

FEATURES

- Trench MOS Schottky technology
- Very low profile - typical height of 1.7 mm
- Ideal for automated placement
- Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified available:
 - Automotive ordering code: base P/NHM3
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

 AUTOMOTIVE
GRADE
Available

RoHS
COMPLIANT
HALOGEN
FREE

TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection in commercial, industrial, and automotive application.

MECHANICAL DATA

Case: SMPD (TO-263AC)

 Molding compound meets UL 94 V-0 flammability rating
 Base P/N-M3 - halogen-free, RoHS-compliant

 Base P/NHM3 - halogen-free, RoHS-compliant, and
 AEC-Q101 qualified

Terminals: matte tin plated leads, solderable per
 J-STD-002 and JESD 22-B102

M3 and HM3 suffix meets JESD 201 class 2 whisker test

Polarity: as marked

MAXIMUM RATINGS ($T_A = 25\text{ °C}$ unless otherwise noted)

| PARAMETER | SYMBOL | V60D100C | UNIT |
|---|----------------|-------------|------------|
| Maximum repetitive peak reverse voltage | V_{RRM} | 100 | V |
| Maximum average forward rectified current (fig. 1) | $I_{F(AV)}$ | per device | 60 |
| | | per diode | 30 |
| Peak forward surge current 10 ms single half sine-wave superimposed on rated load | I_{FSM} | 320 | A |
| Voltage rate of change (rated V_R) | dV/dt | 10 000 | V/ μ s |
| Operating junction and storage temperature range | T_J, T_{STG} | -40 to +150 | °C |



| ELECTRICAL CHARACTERISTICS ($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted) | | | | | | |
|---|----------------------|-----------------------------------|-------------|------|------|---------------|
| PARAMETER | TEST CONDITIONS | | SYMBOL | TYP. | MAX. | UNIT |
| Instantaneous forward voltage per diode | $I_F = 5\text{ A}$ | $T_A = 25\text{ }^\circ\text{C}$ | $V_F^{(1)}$ | 0.45 | - | V |
| | $I_F = 15\text{ A}$ | | | 0.62 | - | |
| | $I_F = 30\text{ A}$ | | | 0.75 | 0.81 | |
| | $I_F = 5\text{ A}$ | $T_A = 125\text{ }^\circ\text{C}$ | | 0.36 | - | |
| | $I_F = 15\text{ A}$ | | | 0.54 | - | |
| | $I_F = 30\text{ A}$ | | | 0.66 | 0.73 | |
| Reverse current at rated V_R per diode | $V_R = 70\text{ V}$ | $T_A = 25\text{ }^\circ\text{C}$ | $I_R^{(2)}$ | 12 | - | μA |
| | | $T_A = 125\text{ }^\circ\text{C}$ | | 11 | - | mA |
| | $V_R = 100\text{ V}$ | $T_A = 25\text{ }^\circ\text{C}$ | | - | 1000 | μA |
| | | $T_A = 125\text{ }^\circ\text{C}$ | | 27 | 85 | mA |

Notes

- (1) Pulse test: 300 μs pulse width, 1 % duty cycle
(2) Pulse test: Pulse width $\leq 5\text{ ms}$

| THERMAL CHARACTERISTICS ($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted) | | | | |
|--|------------|--------------------------|----------|--------------------|
| PARAMETER | | SYMBOL | V60D100C | UNIT |
| Typical thermal resistance | per diode | $R_{\theta JC}$ | 1.8 | $^\circ\text{C/W}$ |
| | per device | $R_{\theta JC}$ | 0.95 | |
| | per device | $R_{\theta JM}^{(2)}$ | 3 | |
| | per device | $R_{\theta JA}^{(1)(2)}$ | 45 | |

Notes

- (1) The heat generated must be less than the thermal conductivity from junction-to-ambient: $dP_D/dT_J < 1/R_{\theta JA}$
(2) Free air, without heatsink; thermal resistance $R_{\theta JA}$ - junction to ambient; thermal resistance $R_{\theta JM}$ - junction to mount

| ORDERING INFORMATION (Example) | | | | | |
|--------------------------------|------------------------------|-----------------|--------------|---------------|------------------------------------|
| PACKAGE | PREFERRED P/N | UNIT WEIGHT (g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE |
| SMPD (TO-263AC) | V60D100C-M3/I | 0.55 | I | 2000/reel | 13" diameter plastic tape and reel |
| SMPD (TO-263AC) | V60D100CHM3/I ⁽¹⁾ | 0.55 | I | 2000/reel | 13" diameter plastic tape and reel |

Note

- (1) AEC-Q101 qualified

RATINGS AND CHARACTERISTICS CURVES ($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)

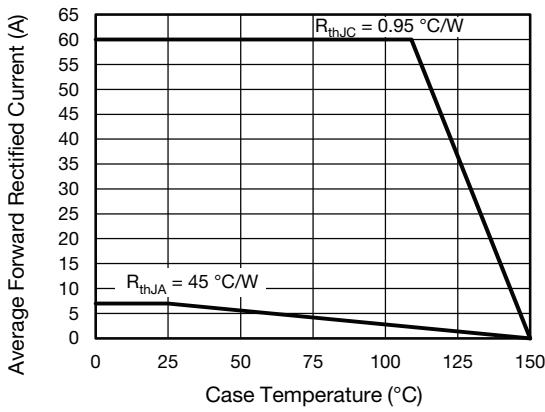


Fig. 1 - Forward Current Derating Curve

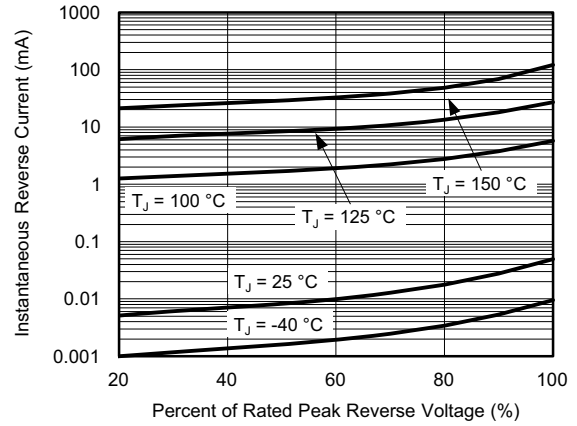


Fig. 4 - Typical Reverse Characteristics Per Diode

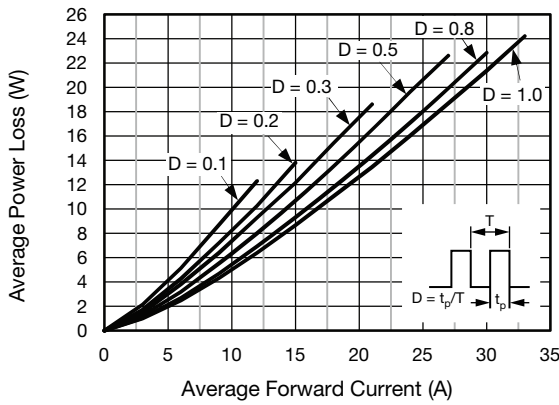


Fig. 2 - Forward Power Loss Characteristics Per Diode

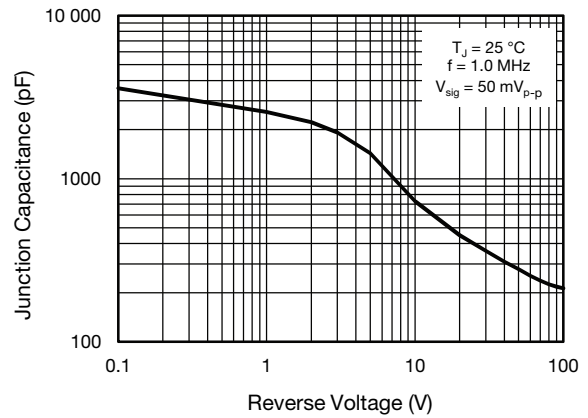


Fig. 5 - Typical Junction Capacitance Per Diode

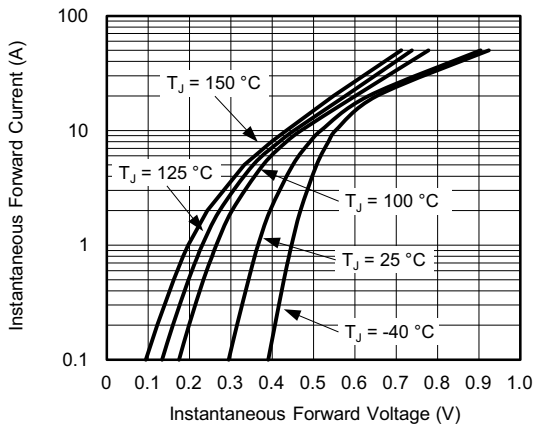


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

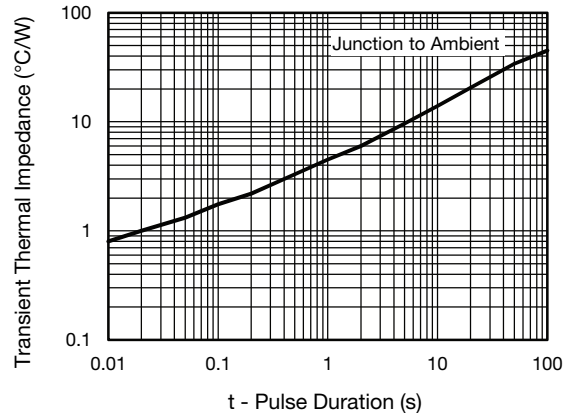


Fig. 6 - Typical Transient Thermal Impedance Per Device

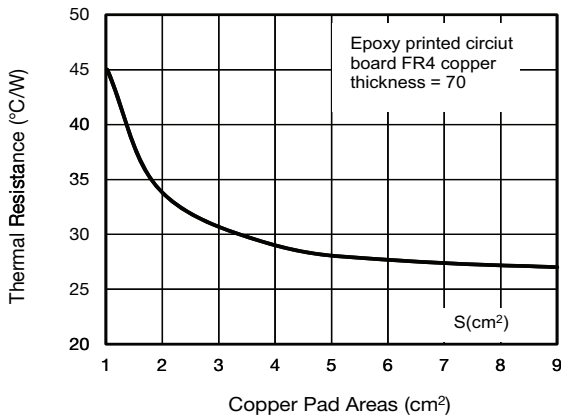
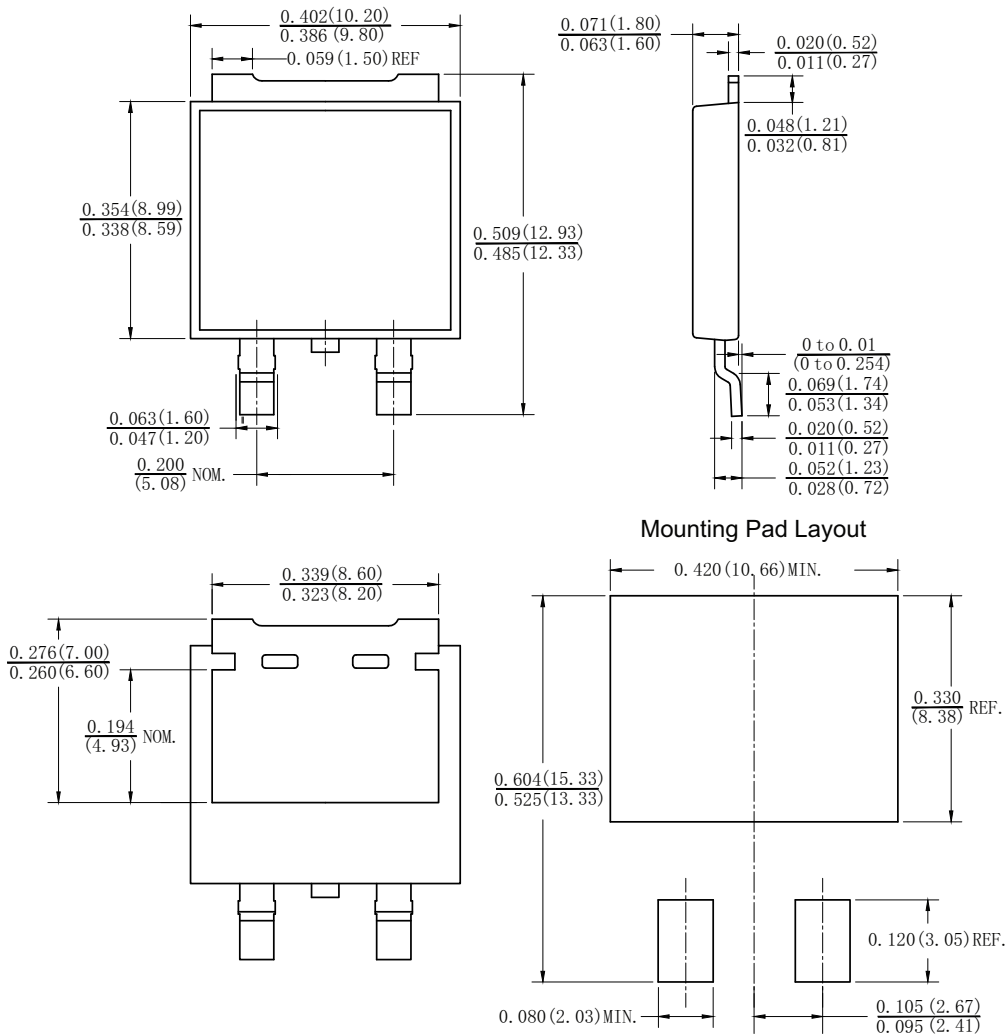


Fig. 7 - Thermal Resistance Junction-to-Ambient vs. Copper Pad Areas

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

SMPD (TO-263AC)





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